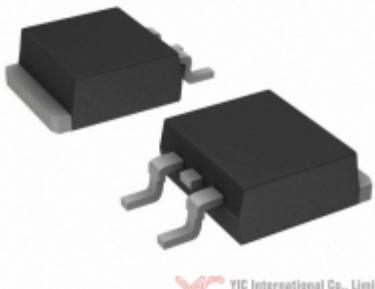






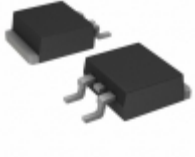

	<h2 style="color: red;">FQB6N50TM</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">FQB6N50TM</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 500V 5.5A D2PAK
<b>Datenblätter:</b>	 <a href="#">FQB6N50TM.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 9198 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">FQB6N50TM</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 500V 5.5A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	9198 pcs Stock
detaillierte Beschreibung	N-Channel 500V 5.5A (Tc) 3.13W (Ta), 130W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 130W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V <sub>dss</sub> )	500V
Strom - Ununterbrochener Abfluss (I <sub>d</sub> ) bei 25 ° C	5.5A (Tc)
R <sub>ds</sub> On (Max) @ I <sub>d</sub> , V <sub>gs</sub>	1.3 Ohm @ 2.8A, 10V
V <sub>GS</sub> (th) (Max) @ I <sub>d</sub>	5V @ 250µA
Gate Charge (Q <sub>g</sub> ) (Max) @ V <sub>gs</sub>	22nC @ 10V
Eingabekapazität (C <sub>iss</sub> ) (Max) @ V <sub>ds</sub>	790pF @ 25V
Antriebsspannung (Max R <sub>ds</sub> On, Min R <sub>ds</sub> On)	10V
V <sub>gs</sub> (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQB6N50TM ist neu im Original, Suche FQB6N50TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB6N50TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB6N50TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB6N45</b> Fairchild/ON Semiconductor FQB6N45 FAIRCHILD</p>	 <p><b>FQB6N60</b> FSC FQB6N60 FSC</p>	 <p><b>FQB6N40CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 400V 6A D2PAK</p>	 <p><b>FQB6N60CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 5.5A D2PAK</p>
 <p><b>FQB6N60C</b> Fairchild/ON Semiconductor FQB6N60C FAIRCHILD</p>	 <p><b>FQB6N50TM</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 5.5A D2PAK</p>	 <p><b>FQB6N60TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 6.2A D2PAK</p>	 <p><b>FQB6N40CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 400V 6A D2PAK</p>

### heiße Teile

Mehr

FQB55N10	FQB55N10TM	FQB55N10TM	FQB5N20L	FQB5N30TM
FQB5N30TM	FQB5N50C	FQB5N50CF	FQB5N50CTM	FQB5N50CTM
FQB5N60CTM	FQB5N60CTM	FQB5N90TM	FQB5N90TM	FQB5P10TM
FQB5P10TM	FQB630TM	FQB630TM	FQB65N06	FQB65N06TM
FQB65N06TM	FQB6N40C	FQB6N40CF	FQB6N40CTM	FQB6N40CTM
FQB6N50TM	FQB6N60C	FQB6N60CTM	FQB6N60CTM	FQB6N60TM
FQB6N60TM	FQB6N70TM	FQB6N70TM	FQB6N90TM	FQB6N90TM_AM002
FQB6N90TM_AM002	FQB7042FB	FQB7045FB	FQB70N03	FQB70N06
FQB70N08	FQB70N10TM	FQB7N10L	FQB7N20L	FQB7N60TM
FQB7N60TM	FQB7N65C	FQB7N65CTM	FQB7N65CTM	FQB7P20TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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